

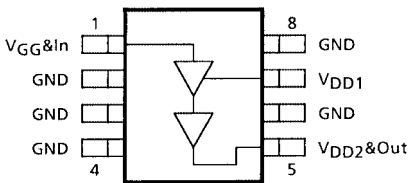
TG2006F

1.9 GHz Band Power Amplifier
PHS, Digital Cordless Telecommunication

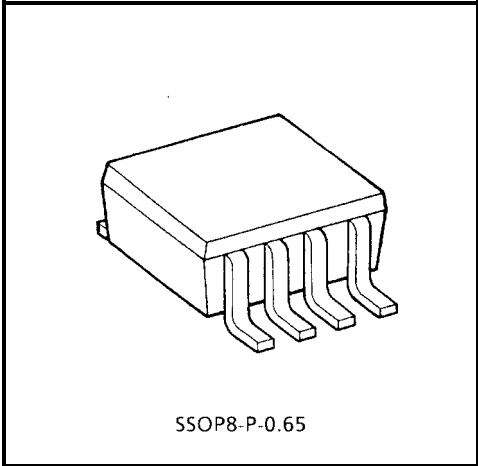
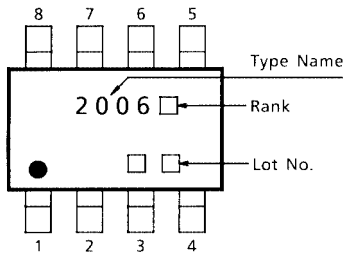
Features

- Positive voltage operation: $V_d = 3\text{ V}$, $V_g = 0$ or 1 V
- Low current consumption: $I_t = 130\text{ mA}$ (typ.)
- Small package: SM8 package ($2.9 \times 2.8 \times 1.1\text{ mm}$)
- Low cost: Can be achieved minimum function.

Pin Assignment (top view)



Marking



Weight: 0.02 g (typ.)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Supply voltage	V_{DD1}	5	V
	V_{DD2}	5	V
Gate voltage	V_{GG}	1	V
Input power	P_i	10	mW
Power dissipation	P_d (Note1)	250	mW
Operating temperature range	T_{opr}	-40~85	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~150	$^\circ\text{C}$

Note 1: When mounted on $2.5\text{ cm}^2 \times 1.6\text{ t}$ glass epoxy board.

Classify Rank

This device is classified by Fig.1.

And satisfy ELECTRICAL CHARACTERISTICS by V_g Condition on each rank.

The rank division is performed for every reel and can't order to choose any rank.

Table 1

Rank	V_g Condition
A	$V_g = 0\text{ V}$
B	$V_g = 1\text{ V}$

Caution

This device is electrostatic sensitivity. Please handle with caution.

Electrical Characteristics

($V_d = 3\text{ V}$, $V_g = (\text{Note 2})$, $f = 1.9\text{ GHz}$, $T_a = 25^\circ\text{C}$, $Z_g = Z_l = 50\ \Omega$, 1/2 duty operation) (Note 4)

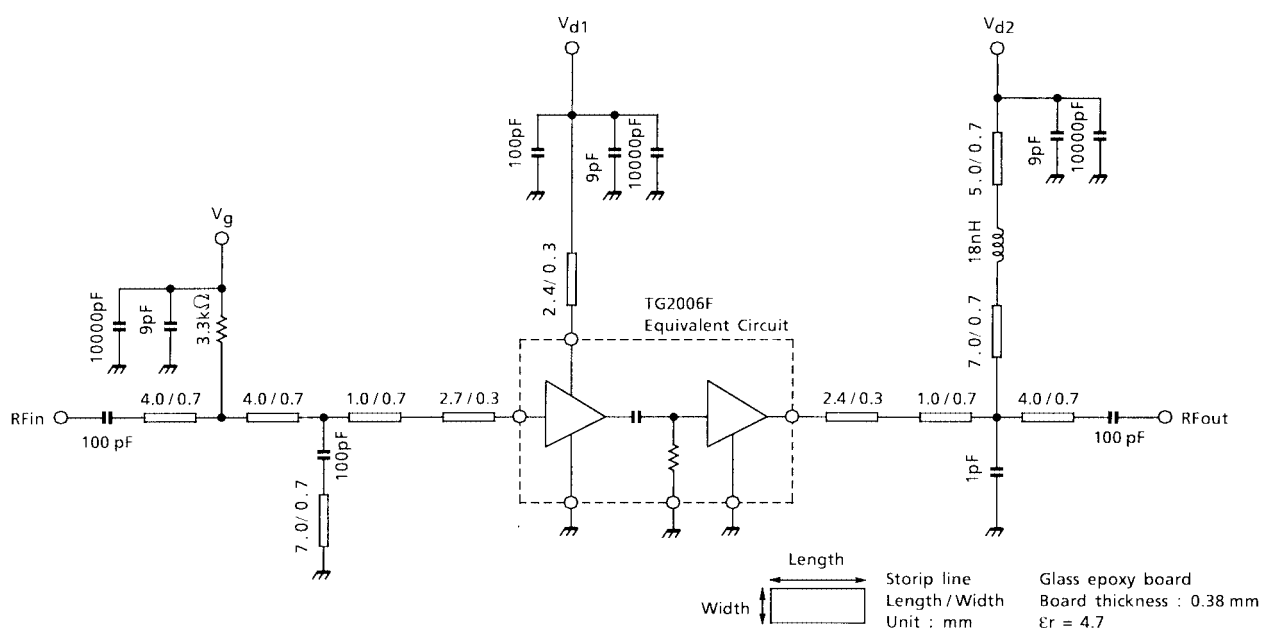
Characteristics	Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Frequency	f _{range}	—	—		1895	—	1918	MHz
Total current	I _t	1	P _O = 21dBmW, P _i = Regulation		—	130	150	mA
Gate current	I _G	1			—	—	1	
Output power	P _O	1	P _i = 1dBmW		21	—	—	dBmW
Small signal gain	G _p	1	P _i = -20dBmW		21	23	—	dB
Adjacent channel leakage power ratio	ACP (1)	1	P _O = 21dBmW, P _i = Regulation (Note 3)	Δf = 600 kHz	—	-60	-55	dB
	ACP (2)	1		Δf = 900 kHz	—	-65	-60	
Harmonics	2f ₀	1	P _O = 21dBmW, P _i = Regulation		—	—	-30	dB
	3f ₀	1			—	—	-30	
Input VSWR	VSWR _{in}	1	P _O = 21dBmW, P _i = Regulation		—	1.5	2.5	—
Load mismatch	—	—	V _d = 4.0V, V _g = (Note 2), P _O = 21dBmW, P _i = Regulation, Z _g = 50 Ω, VSWR Load = 20 : 1 all phase		No Degradation			—
Stability	—	—	V _d = 2.7~4.0V, V _g = (Note 2), P _i = -2dBmW~4dBmW, Z _g = 50 Ω VSWR Load = 6: 1 all phase		All spurious output than 60dB below desired signal			—

Note 2: V_g Voltage is decided on Fig.1.

Note 3: Input signal is modulated to $\pi/4$ QPSK ($\alpha = 0.5$). Bit rate is 384 kbps.

Note 4: $V_d = V_{d1} = V_{d2}$, $I_t = I_{d1} + I_{d2}$

Test Circuit 1 (RF test circuit)



Notice

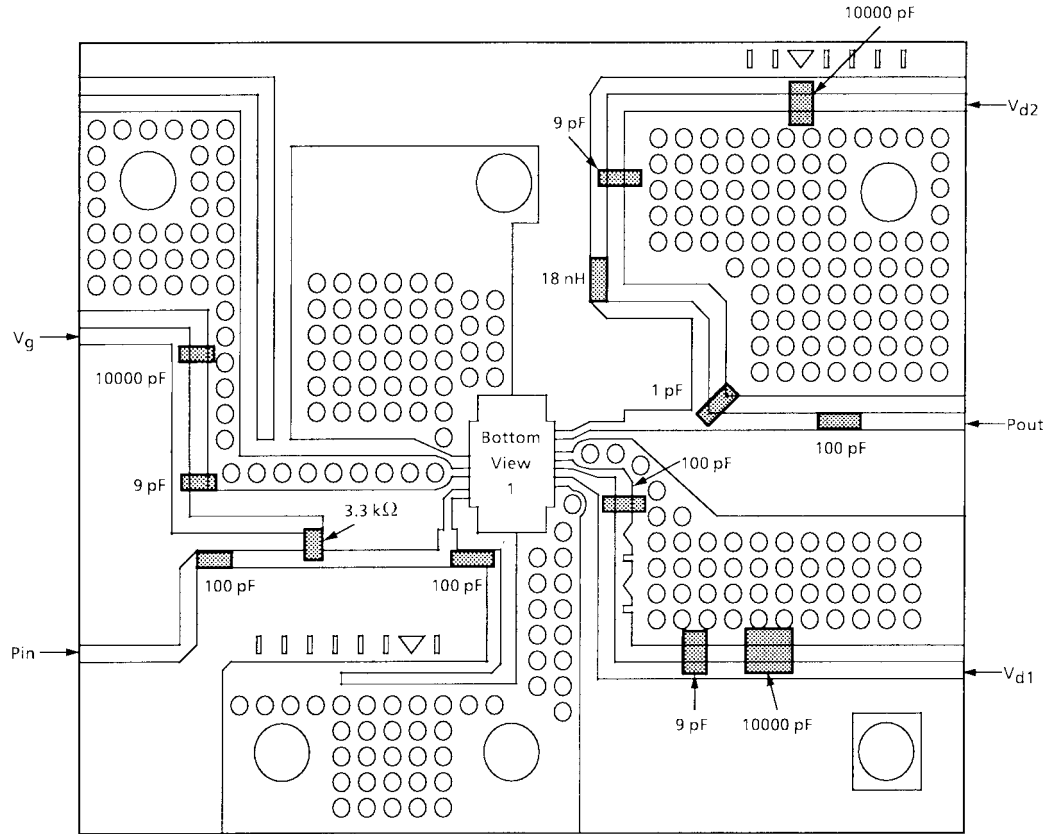
The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

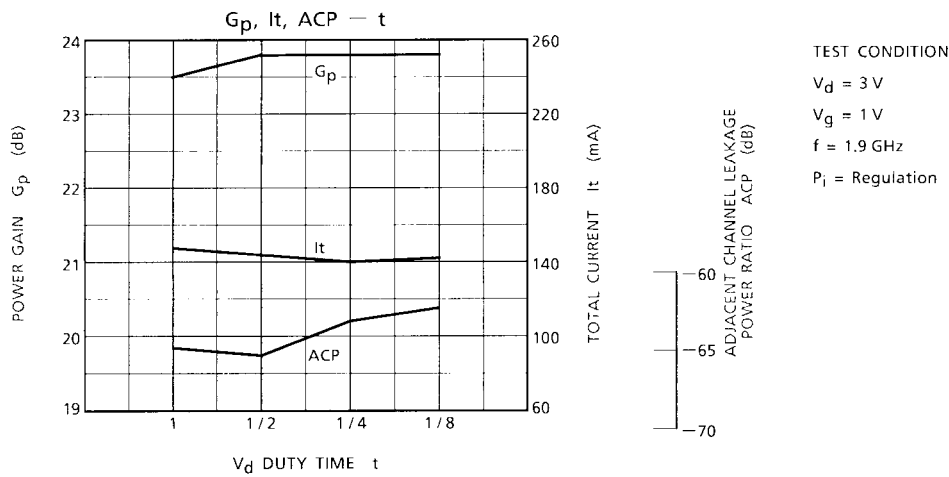
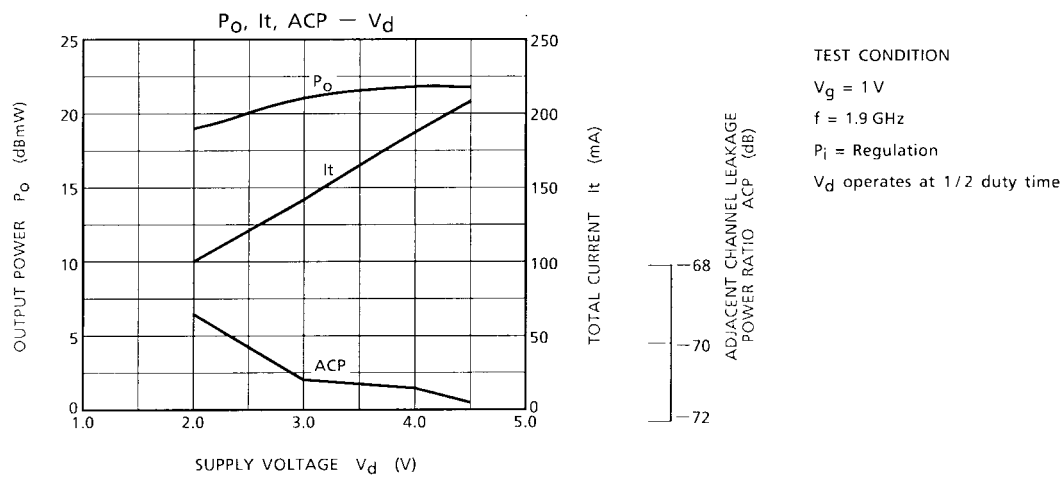
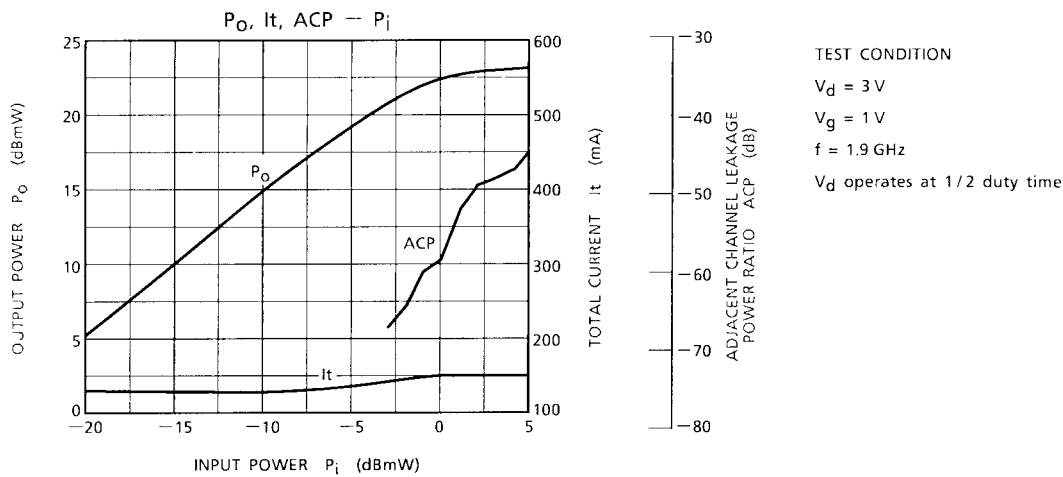
Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

TOSHIBA assume no responsibility for the integrity of customer circuit designs or applications.

RF Test Board

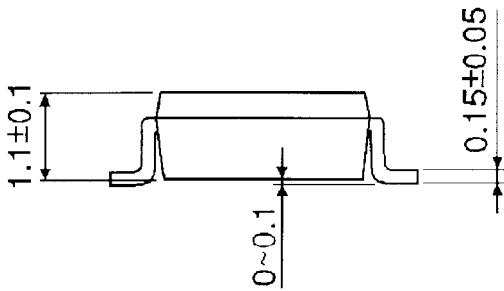
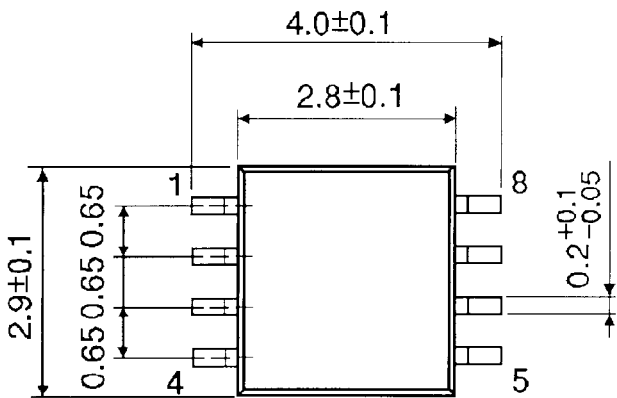




Package Dimensions

SSOP8-P-0.65

Unit : mm



Weight : 0.02 g (Typ.)

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020704EAC

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